

PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Docket No: Q95660

Katsumi KUSHIYA, et al.

Appln. No.: Based on PCT/JP04/019693

Confirmation No.: Unknown

Group Art Unit: Unknown

Filed: June 26, 2006

Examiner: Unknown

For: INTEGRATED THIN-FILM SOLAR CELL AND PROCESS FOR PRODUCING THE SAME

INFORMATION DISCLOSURE STATEMENT
UNDER 37 C.F.R. §§ 1.97 and 1.98

MAIL STOP AMENDMENT

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

Sir:

In accordance with the duty of disclosure under 37 C.F.R. § 1.56, Applicant hereby notifies the U.S. Patent and Trademark Office of the documents which are listed on the attached PTO/SB/08 A & B (modified) form and/or listed herein and which the Examiner may deem material to patentability of the claims of the above-identified application.

One copy of each of the listed documents is submitted herewith, except for the following: U.S. patents and/or U.S. patent publications; and co-pending non-provisional U.S. applications filed after June 30, 2003.

The present Information Disclosure Statement is being filed: (1) No later than three months from the application's filing date; (2) Before the mailing date of the first Office Action on the merits (whichever is later); or (3) Before the mailing date of the first Office Action after

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AP3 Rec'd PCT/PTO 26 JUN 2006

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filing a request for continued examination (RCE) under §1.114, and therefore, no Statement under 37 C.F.R. § 1.97(e) or fee under 37 C.F.R. § 1.17(p) is required.

In compliance with the concise explanation requirement under 37 C.F.R. § 1.98(a)(3) for foreign language documents, Applicant encloses herewith a copy of a Communication from a foreign patent office in a counterpart application citing such documents (International Search Reprot for PCT/JP04/019693 dated March 15, 2005), together with an English-language version (if not already included) of at least that portion of the Communication indicating the degree of relevance found by the foreign patent office.

The submission of the listed documents is not intended as an admission that any such document constitutes prior art against the claims of the present application. Applicant does not waive any right to take any action that would be appropriate to antedate or otherwise remove any listed document as a competent reference against the claims of the present application.

The USPTO is directed and authorized to charge all required fees, except for the Issue Fee and the Publication Fee, to Deposit Account No. 19-4880. Please also credit any overpayments to said Deposit Account.

Respectfully submitted,

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Date: June 26, 2006

Substitute for Form 1449 A & B/PTO

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

(use as many sheets as necessary)

Sheet 1 of 1

Application Number	Based on PCT/JP04/019693
Confirmation Number	Unknown
Filing Date	June 26, 2006
First Named Inventor	Katsumi KUSHIYA
Art Unit	Unknown
Examiner Name	Unknown
Attorney Docket Number	Q95660

U.S. PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Document Number		Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document
		Number	Kind Code ² (if known)		
		US 5,477,088	A	12-19-1995	Angus A. Rockett, et al.
		US			
		US			
		US			
		US			
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		US			
		US			

FOREIGN PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Foreign Patent Document			Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Translation ⁶
		Country Code ³	Number ⁴	Kind Code ⁵ (if known)			
		JP	2002-319686	A	10-31-2002	Matsushita Electric Industrial Co., Ltd.	
		JP	10-200142	A	07-31-1998	Yazaki Corp.	
		JP	4-94174	A	03-26-1992	Fuji Electric Co., Ltd.	
		JP	2001-156026	A	06-08-2001	Canon Inc.	
		JP	11-345989	A	12-14-1999	Matsushita Battery Industrial Co., Ltd.	

NON PATENT LITERATURE DOCUMENTS

Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city, and/or country where published.	Translation ⁶
		T. WADA, et al., "Characterization of the Cu(In,Ga)Se ₂ /Mo interface in CIGS solar cells". Thin Solid Films, 2001, pp. 118-122, Vol. 387	
		J. ALVAREZ-GARCIA, et al., "Microstructure and secondary phases in coevaporated CuInS ₂ films: Dependence on growth temperature and chemical composition", Journal of Vacuum science & Technology A, January/February 2001, pp. 232-239, Vol. 19	
		International Search Report for PCT/JP04/019693 dated March 15, 2005	

Examiner Signature	/Brian Walck/	Date Considered	01/27/2010
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*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹ Applicant's unique citation designation number (optional). ² See Kind Codes of USPTO Patent Documents at www.uspto.gov, MPEP 901.04 or follow the hyperlink from the title of the document to the internet. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST. 3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁶ Applicants is to indicate here if English language Translation is attached.